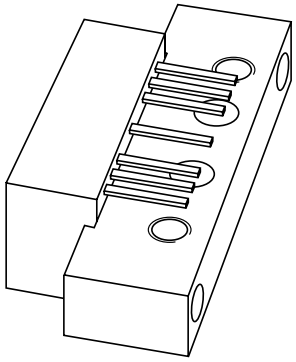
DATA SHEET



BGY587
550 MHz, 22 dB gain push-pull amplifier

Product specification
Supersedes data of 1994 Feb 07

2001 Nov 27

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550 MHz, 22 dB gain push-pull amplifier BGY587

FEATURES

Excellent linearity

- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

APPLICATIONS

- CATV systems operating in the 40 to 550 MHz frequency range.

DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC). The BGY587 is intended for use as a final amplifier.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2, 3	common
5	$+V_B$
7, 8	common
9	output

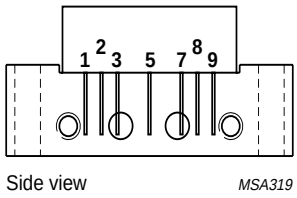


Fig.1 Simplified outline.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G_p	power gain	f = 50 MHz	21.5	–	22.5	dB
		f = 550 MHz	22	–	–	dB
I_{tot}	total current consumption (DC)	V_B = 24 V	–	220	240	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V_i	RF input voltage	–	65	dBmV
T_{stg}	storage temperature	–40	+100	°C
T_{mb}	operating mounting base temperature	–20	+100	°C

CHARACTERISTICS

Bandwidth 40 to 550 MHz; V_B = 24 V; T_{mb} = 30 °C; $Z_S = Z_L$ = 75 Ω.

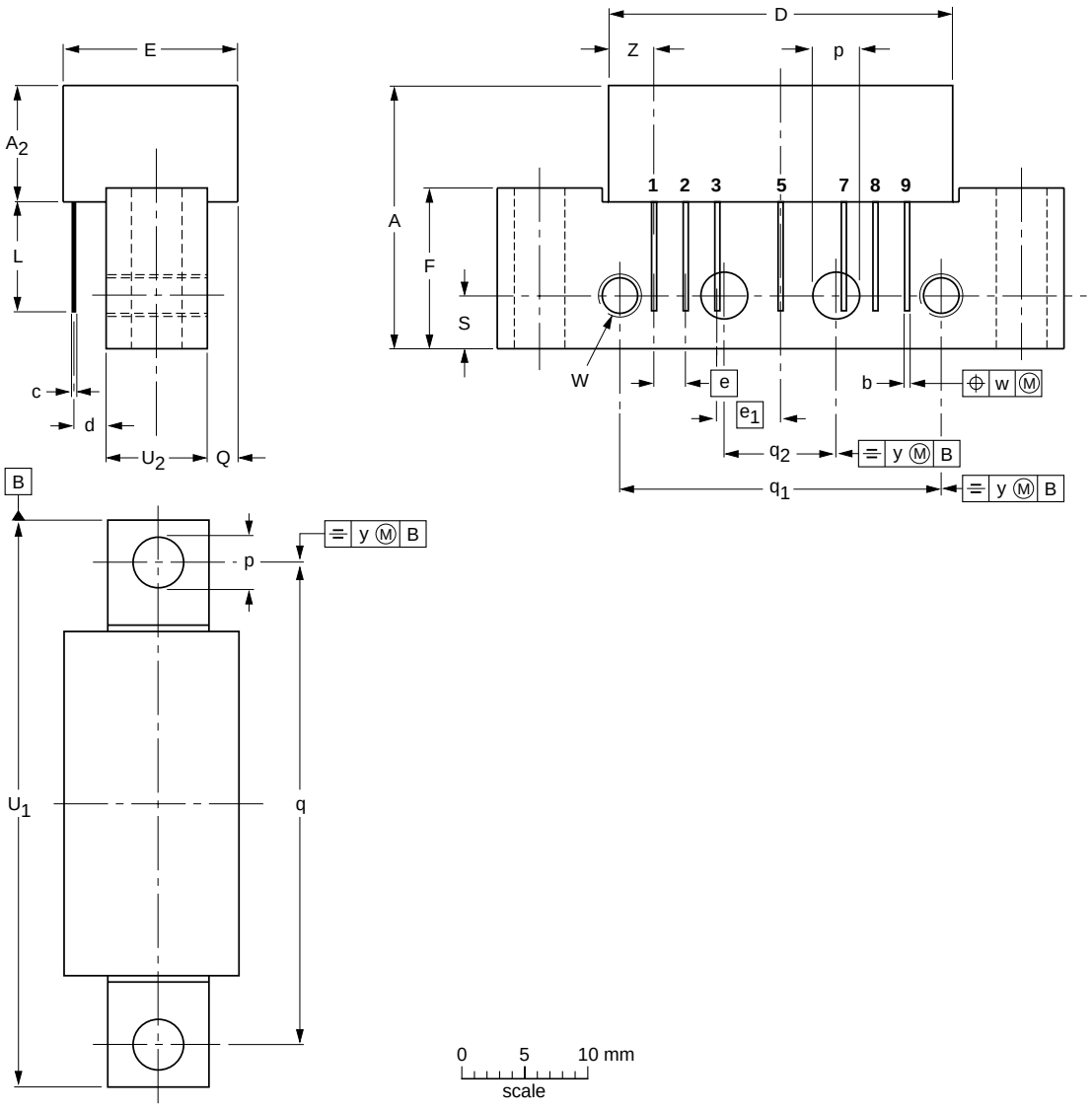
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G_p	power gain	f = 50 MHz	21.5	–	22.5	dB
		f = 550 MHz	22	–	–	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	–	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	–	–	±0.2	dB
s_{11}	input return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	19	–	–	dB
		f = 160 to 550 MHz	18	–	–	dB
s_{22}	output return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	19	–	–	dB
		f = 160 to 550 MHz	18	–	–	dB
s_{21}	phase response	f = 50 MHz	+135	–	+225	deg
CTB	composite triple beat	77 channels flat; V_o = 44 dBmV; measured at 547.25 MHz	–	–	–57	dB
X_{mod}	cross modulation	77 channels flat; V_o = 44 dBmV; measured at 55.25 MHz	–	–	–58	dB
CSO	composite second order distortion	77 channels flat; V_o = 44 dBmV; measured at 548.5 MHz	–	–	–54	dB
d_2	second order distortion	note 1	–	–	–66	dB
V_o	output voltage	d_{im} = –60 dB; note 2	61	–	–	dBmV
NF	noise figure	f = 550 MHz	–	–	7	dB
I_{tot}	total current consumption (DC)	note 3	–	220	240	mA

Notes

1. f_p = 55.25 MHz; V_p = 44 dBmV;
   f_q = 493.25 MHz; V_q = 44 dBmV;
   measured at $f_p + f_q$ = 548.5 MHz.
2. Measured according to DIN45004B:
   f_p = 540.25 MHz; $V_p = V_o$;
   f_q = 547.25 MHz; $V_q = V_o$ –6 dB;
   f_r = 549.25 MHz; $V_r = V_o$ –6 dB;
   measured at $f_p + f_q - f_r$ = 538.25 MHz.
3. The module normally operate at V_B = 24 V, but is able to withstand supply transients up to 30 V.

PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads **SOT115J**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_2 max.	b	c	D max.	d max.	E max.	e	e_1	F	L min.	p	Q max.	q	q_1	q_2	S	U_1 max.	U_2	W	w	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75	8	6-32 UNC	0.25	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT115J						99-02-06

DATA SHEET STATUS

DATA SHEET STATUS[1]	PRODUCT STATUS[2]	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

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CAUTION
This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A, and SNW-FQ-302B.

NOTES

NOTES

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